# FAIRCHILD

SEMICONDUCTOR®

# TIP145T/146T/147T

## Monolithic Construction With Built In Base-Emitter Shunt Resistors

High DC Current Gain : h<sub>FE</sub> = 1000@ V<sub>CE</sub> = - 4V, I<sub>C</sub> = - 5A (Min.)

Industrial Use

• Complement to TIP140T/141T/142T

# **PNP Epitaxial Silicon Darlington Transistor**

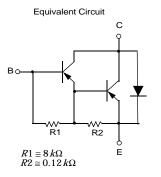
## Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage : TIP14		V
CBO	: TIP14		v
	: TIP14		v
	Collector-Emitter Voltage : TIP14	45T - 60	V
V <sub>CEO</sub>	: TIP14	46T - 80	V
020	: TIP14	47T - 100	V
V <sub>EBO</sub>	Emitter-Base Voltage	- 5	V
I <sub>C</sub>	Collector Current (DC)	- 10	Α
I <sub>CP</sub>	Collector Current (Pulse)	- 15	A
I <sub>B</sub>	Base Current (DC)	- 0.5	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	80	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C



TIP145T/146T/147T

1.Base 2.Collector 3.Emitter

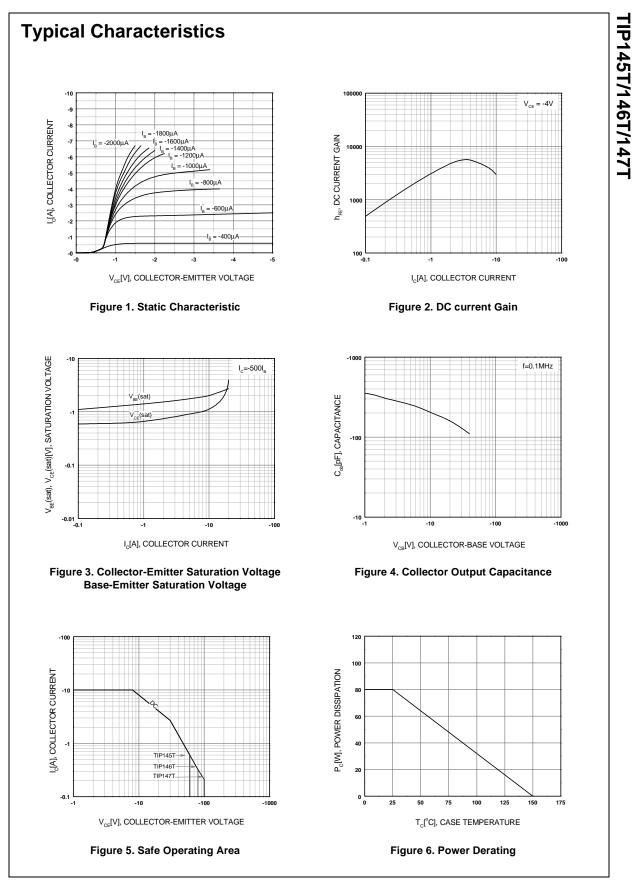


Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	Collector-Emitter Sustaining Voltage : TIP145T : TIP146T : TIP147T	I <sub>C</sub> = - 30mA, I <sub>B</sub> = 0	- 60 - 80 - 100			V V V
I <sub>CEO</sub>	Collector Cut-off Current : TIP145T : TIP146T : TIP147T	$V_{CE} = -30V, I_B = 0$ $V_{CE} = -40V, I_B = 0$ $V_{CE} = -50V, I_B = 0$			- 2 - 2 - 2	mA mA mA
I <sub>CBO</sub>	Collector Cut-off Current : TIP145T : TIP146T : TIP147T	$V_{CB} = -60V, I_E = 0$ $V_{CB} = -80V, I_E = 0$ $V_{CB} = -100V, I_E = 0$			- 1 - 1 - 1	mA mA mA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{BE} = -5V, I_{C} = 0$			- 2	mA
h <sub>FE</sub>	DC Current Gain	$V_{CE} = -4V, I_{C} = -5A$ $V_{CE} = -4V, I_{C} = -10A$	1000 500			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_{C} = -5A, I_{B} = -10mA$ $I_{C} = -10A, I_{B} = -40mA$			- 2 - 3	V V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = - 10A, I <sub>B</sub> = - 40mA			- 3.5	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> = - 4V, I <sub>C</sub> = - 10A			- 3	V
t <sub>D</sub>	Delay Time	V <sub>CC</sub> = - 30V, I <sub>C</sub> = - 5A		0.15		μs
t <sub>R</sub>	Rise Time	$I_{B1} = -20 \text{mA}, I_{B2} = 20 \text{mA}$		0.55		μs
t <sub>STG</sub>	Storage Time	$R_L = 6\Omega$		2.5		μs
t <sub>F</sub>	Fall Time			2.5		μs

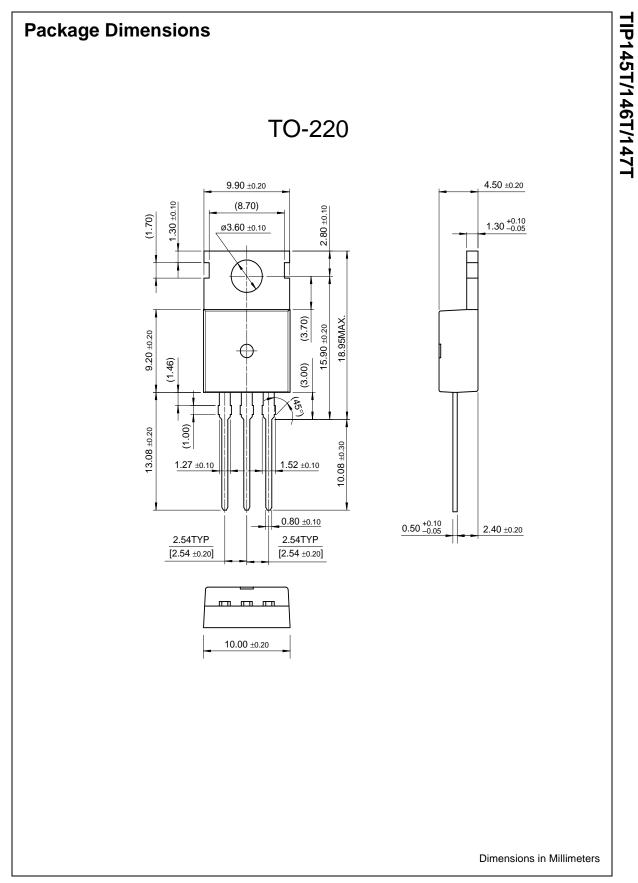
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